



International Semiconductor, Inc.

5 WATT ZENER DIODES

HIGH SURGE CURRENT CAPABILITY 3.3 TO 200 VOLTS

**1N5333B
thru
1N5388B**

*** ELECTRICAL CHARACTERISTICS @ 25°C**

TYPE NUMBER	REGULATOR VOLTAGE (V _Z)	TEST CURRENT (I _Z)	MAXIMUM DYNAMIC IMPEDANCE (Z _d) (A&B Suffix)	MAXIMUM REVERSE CURRENT (I _r)	I _Z TEST VOLTAGE (V _Z) (Non-Suffix & A Suffix)	I _Z TEST VOLTAGE (V _Z) (B, C, D Suffix)	MAXIMUM REGULATOR CURRENT (I _{ZM}) (A, B, C, D Suffix)	MAXIMUM DYNAMIC KNEE IMPEDANCE (Z _{zk} at 1.0 mA) (A, B, C, D Suffix)	MAXIMUM SURGE CURRENT (I _{ZSM})	MAXIMUM VOLTAGE REGULATION (ΔV _Z) (A, B, C, D Suffix)
	V	mA dc	OHMS	μA	V	V	mA	OHMS	AMPS	VOLTS
1N5333B	3.3	380	3.0	300	1.0	1.0	1440	400	20	0.85
1N5334B	3.6	350	2.5	150	1.0	1.0	1320	500	18.7	0.80
1N5335B	3.9	320	2.0	50	1.0	1.0	1220	500	17.6	0.54
1N5336B	4.3	290	2.0	10	1.0	1.0	1100	500	16.4	0.49
1N5337B	4.7	260	2.0	5.0	1.0	1.0	1010	450	15.3	0.44
1N5338B	5.1	240	1.5	1.0	1.0	1.0	930	400	14.4	0.39
1N5339B	5.6	220	1.0	1.0	2.0	2.0	865	400	13.4	0.25
1N5340B	6.0	200	1.0	1.0	3.0	3.0	790	300	12.7	0.19
1N5341B	6.2	200	1.0	1.0	3.0	3.0	765	200	12.4	0.10
1N5342B	6.8	175	1.0	1.0	4.9	5.2	700	200	11.5	0.15
1N5343B	7.5	175	1.5	10	5.4	5.7	630	200	10.7	0.15
1N5344B	8.2	150	1.5	10	5.9	6.2	580	200	10	0.20
1N5345B	8.7	150	2.0	10	6.25	6.6	545	200	9.5	0.20
1N5346B	9.1	150	2.0	7.5	6.6	6.9	520	150	9.2	0.22
1N5347B	10	125	2.0	5.0	7.2	7.6	475	125	8.6	0.22
1N5348B	11	125	2.5	5.0	8.0	8.4	430	125	8.0	0.25
1N5349B	12	100	2.5	2.0	8.6	9.1	395	125	7.5	0.25
1N5350B	13	100	2.5	1.0	9.4	9.9	365	100	7.0	0.25
1N5351B	14	100	2.5	1.0	10.1	10.6	340	75	6.7	0.25
1N5352B	15	75	2.5	1.0	10.8	11.5	315	75	6.3	0.25
1N5353B	16	75	2.5	1.0	11.5	12.2	295	75	6.0	0.30
1N5354B	17	70	2.5	0.5	12.2	12.9	280	75	5.8	0.35
1N5355B	18	65	2.5	0.5	13	13.7	264	75	5.5	0.40
1N5356B	19	65	3.0	0.5	13.7	14.4	250	75	5.3	0.40
1N5357B	20	65	3.0	0.5	14.4	15.2	237	75	5.1	0.40
1N5358B	22	50	3.5	0.5	15.8	16.7	216	75	4.7	0.45
1N5359B	24	50	3.5	0.5	17.3	18.2	198	100	4.4	0.55
1N5360B	25	50	4.0	0.5	18	19	190	110	4.3	0.55
1N5361B	27	50	5.0	0.5	19.4	20.6	176	120	4.1	0.60
1N5362B	28	50	6.0	0.5	20.1	21.2	170	130	3.9	0.60
1N5363B	30	40	8.0	0.5	21.6	22.8	158	140	3.7	0.60
1N5364B	33	40	10	0.5	23.8	25.1	144	150	3.5	0.60
1N5365B	36	30	11	0.5	25.9	27.4	132	160	3.3	0.65
1N5366B	39	30	14	0.5	28.1	29.7	122	170	3.1	0.65
1N5367B	43	30	20	0.5	31	32.7	110	190	2.8	0.70
1N5368B	47	25	25	0.5	33.8	35.8	100	210	2.7	0.80
1N5369B	51	25	27	0.5	36.7	38.8	93	230	2.5	0.90
1N5370B	56	20	35	0.5	40.3	42.6	86	280	2.3	1.00
1N5371B	60	20	40	0.5	43	45.5	79	350	2.2	1.20
1N5372B	62	20	42	0.5	44.6	47.1	76	400	2.1	1.35
1N5373B	68	20	44	0.5	49	51.7	70	500	2.0	1.50
1N5374B	75	20	45	0.5	54	56	63	620	1.9	1.60
1N5375B	82	15	65	0.5	59	62.2	58	720	1.8	1.80
1N5376B	87	15	75	0.5	63	66	54.5	760	1.7	2.00
1N5377B	91	15	75	0.5	65.5	69.2	52.5	760	1.6	2.20
1N5378B	100	12	90	0.5	72	76	47.5	800	1.5	2.30
1N5379B	110	12	125	0.5	79.2	83.6	43	1000	1.4	2.50
1N5380B	120	10	170	0.5	86.4	91.2	39.5	1150	1.3	2.50
1N5381B	130	10	190	0.5	93.6	98.8	36.6	1250	1.2	2.50
1N5382B	140	8.0	230	0.5	101	106	34	1500	1.2	2.50
1N5383B	150	8.0	330	0.5	108	114	31.6	1500	1.1	3.00
1N5384B	160	8.0	350	0.5	115	122	29.4	1650	1.1	3.00
1N5385B	170	8.0	380	0.5	122	129	28	1750	1.0	3.00
1N5386B	180	5.0	430	0.5	130	137	26.4	1750	1.0	4.00
1N5387B	190	5.0	450	0.5	137	144	25	1850	0.9	5.00
1N5388B	200	5.0	480	0.5	144	152	23.6	1850	0.9	5.00

* JEDEC Registered Data.

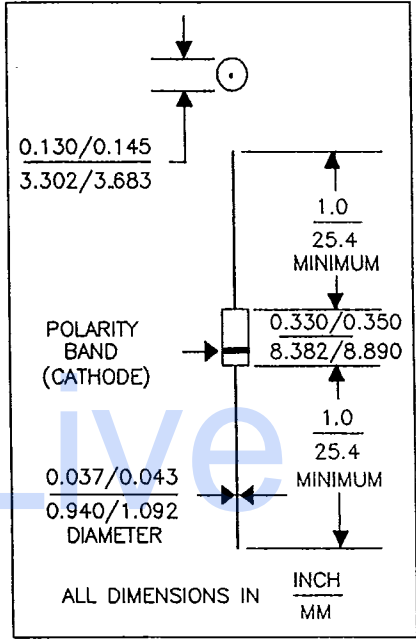


FIGURE 1

MECHANICAL CHARACTERISTICS

- CASE: Void free, transfer molded, thermosetting plastic
- FINISH: Corrosion resistant, readily solderable
- POLARITY: Cathode Banded.
- WEIGHT: 0.7 Grams (approx.)
- MOUNTING POSITION: Any

MAXIMUM RATINGS

- OPERATING TEMPERATURE: -65C to +200C
- DC POWER DISSIPATION: 5 Watts
- POWER DERATING: 40mW/C above 75C
- FORWARD VOLTAGE @ 1.0 A: 1.2 Volts

CORPORATE OFFICES:

727 Raritan Road - Suite 203
Clark, NJ 07066
Tel: 908 396-0322
Fax: 908 396-0410

SALES OFFICE:

674 E. Alamo, #40
Chandler, AZ 85225
Tel: 602 497-8172
Fax: 602 497-8173

1N5333B thru 1N5388B

49E D ■ 9000378 0000037 788 ■ ISEM

NOTE 1 Devices listed have a $\pm 5\%$ tolerance on nominal V_Z . The suffix A denotes a $\pm 10\%$, C denotes $\pm 2\%$, D denotes $\pm 1\%$, and no suffix denotes a $\pm 20\%$ tolerance.

NOTE 2 Nominal Zener Voltage (V_Z) is read with the device in standard test clips with 3/8 to 1/2 inch spacing between clip and case of the diode. Before reading the diode is allowed to stabilize for a period of 40 ± 10 milliseconds at 25°C ($+8, -2^\circ\text{C}$).

NOTE 3 The Zener Impedance (Z_{ZT} or Z_{ZK}) is derived from the 60 Hz ac voltage, which results when an ac current having a rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} respectively.

NOTE 4 The Maximum Reverse (leakage) Current is specified for devices with $\pm 20\%$ and $\pm 10\%$ voltage tolerances on nominal V_Z in another column.

NOTE 5 The Maximum Zener Current (I_{ZM}) shown is for $\pm 5\%$ tolerance devices. I_{ZM} for $\pm 10\%$ and $\pm 20\%$ devices can be calculated using the formula:

$$I_{ZM} = \frac{P}{V_{ZM}}$$

where " V_{ZM} " is V_Z at the high end of the voltage tolerance specified and " P " is the rated power of the device.

NOTE 6 The Surge Current (I_{ZSM}) is specified as the maximum peak of a nonrecurrent sine wave of 8.3 milliseconds duration.

NOTE 7 Voltage Regulation (ΔV_Z) is the difference between the voltage measured at 10% and 50% of I_{ZM} .

INTERNATIONAL SEMICOND

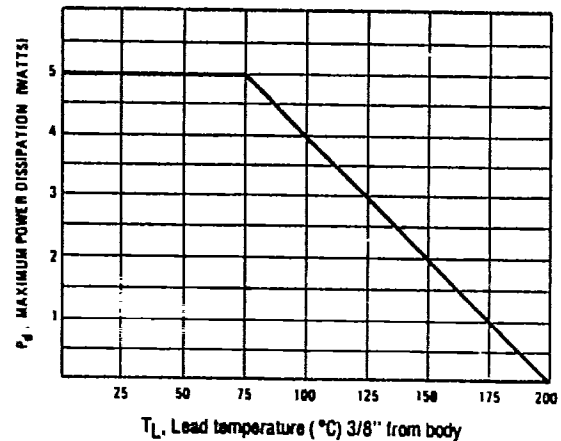


FIGURE 2 POWER DERATING CURVE

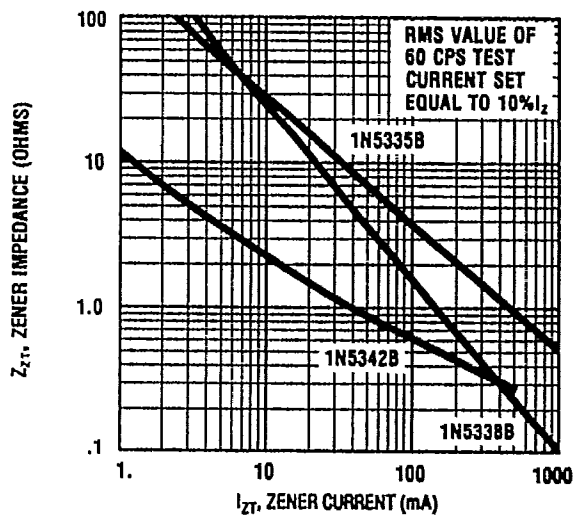


FIGURE 3
TYPICAL ZENER IMPEDANCE VS. ZENER CURRENT FOR TYPES SHOWN

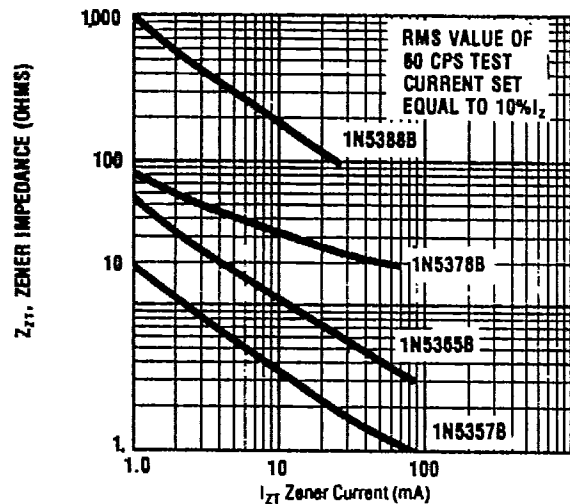


FIGURE 4
TYPICAL ZENER IMPEDANCE VS. ZENER CURRENT FOR TYPES SHOWN

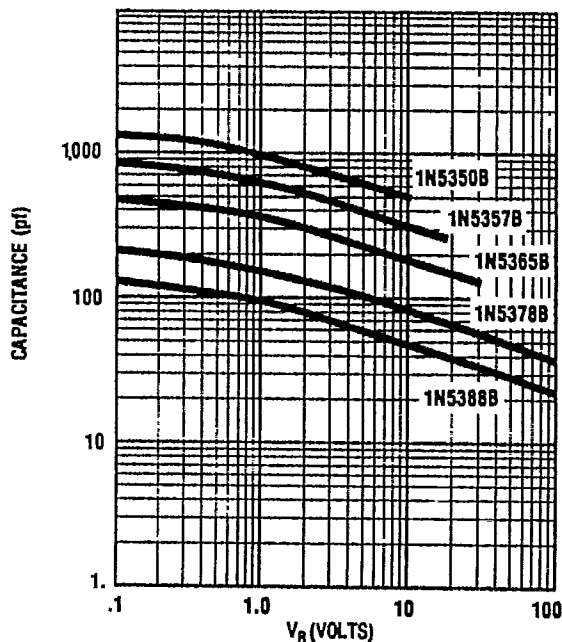


FIGURE 5
TYPICAL CAPACITANCE VS. REVERSE VOLTAGE FOR 5 WATT ZENERS

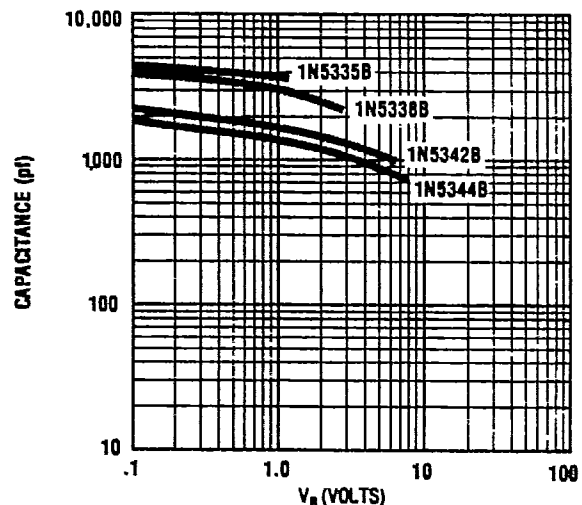


FIGURE 6
TYPICAL CAPACITANCE VS. REVERSE VOLTAGE FOR 5 WATT ZENERS